NSN 5962-01-340-9355

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View Online at https://aerobasegroup.com/nsn/5962-01-340-9355

Overall Height: 0.400 inches **Body Length:** 1.280 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Maximum Power Dissipation Rating:** 1.02 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and bipolar and monolithic **Inclosure Material:** Ceramic Inclosure Configuration: Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** D-9 mil-m-38510 **Current Rating Per Characteristic:** 185.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -500.0 millivolts power source and 7.0 volts power source **Capitance Rating Per Characteristic:** Err-060 and err-060 **Time Rating Per Chacteristic:** 30.00 nanoseconds af output torr Memory Device Type: Prom **Unpackaged Unit Weight:** 6.5 grams **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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